

<b>SI7794DP-T1-GE3</b>	
Numero di parte	<a href="#">SI7794DP-T1-GE3</a>
fabbricante	<a href="#">Electro-Films (EFI) / Vishay</a>
Descrizione	MOSFET N-CH 30V P-PACK SO-8
quantità disponibile	2798 pcs in stock
Schede tecniche	<a href="#">SI7794DP-T1-GE3.pdf</a>
SI7794DP-T1-GE3 Price	<a href="#">Richiedi prezzo e tempi di consegna online</a> or Email us: <a href="mailto:Info@ariat-tech.com">Info@ariat-tech.com</a>


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Informazioni tecniche di SI7794DP-T1-GE3			
codice articolo del costruttore	<a href="#">SI7794DP-T1-GE3</a>	Categoria	<a href="#">Prodotti a semiconduttore discreti</a>
fabbricante	<a href="#">Electro-Films (EFI) / Vishay</a>	Descrizione	MOSFET N-CH 30V P-PACK SO-8
Pacchetto / caso	Tape & Reel (TR)	quantità disponibile	2798
Descrizione dettagliata	N-Channel 30V 28.6A (Ta), 60A (Tc) 5W (Ta), 48W (Tc) Surface Mount PowerPAK® SO-8	Serie	SkyFET®, TrenchFET® Gen III
Tecnologia	MOSFET (Metal Oxide)	temperatura di esercizio	-55°C ~ 150°C (Tj)
Tipo montaggio	Surface Mount	Contenitore / involucro	PowerPAK® SO-8
Contenitore dispositivo fornitore	PowerPAK® SO-8	Dissipazione di potenza (max)	5W (Ta), 48W (Tc)
Tipo FET	N-Channel	Caratteristica FET	Schottky Diode (Body)
Tensione drain-source (Vdss)	30V	Corrente - Drain continuo (Id) @ 25 ° C	28.6A (Ta), 60A (Tc)
Rds On (max) a Id, Vgs	3.4 mOhm @ 20A, 10V	Vgs (th) (max) a Id	2.5V @ 250µA
Carica Gate (Qg) (Max) @ Vgs	72nC @ 10V	Capacità di ingresso (Ciss) (Max) @ Vds	2.52nF @ 15V
Tensione dell'azionamento (Max Rds On, Min Rds On)	4.5V, 10V	Vgs (Max)	±20V
imballaggio	Tape & Reel (TR)	Stato senza piombo / Stato RoHS	Lead free / RoHS Compliant
Moisture Sensitivity Level (MSL)	1 (Unlimited)		

SI7794DP-T1-GE3 2798 pezzi Nuovo e originale in magazzino, trova SI7794DP-T1-GE3 Stock, scheda tecnica, PDF, inventario presso Ariat-Tech .com online, ordina SI7794DP-T1-GE3 Electro-Films (EFI) / Vishay con garanzia e garanzia. RFQ SI7794DP-T1-GE3: [Info@Ariat-Tech.com](mailto:Info@Ariat-Tech.com)

Parti correlate per SI7794DP-T1-GE3				
Immagine	Numero di parte	Descrizione	fabbricante	Quantità
	<a href="#">SI7802DN-T1-E3</a>	MOSFET N-CH 250V 1.24A 1212-8	Electro-Films (EFI) / Vishay	74 pcs
	<a href="#">SI7790DP-T1-E3</a>	SI7790DP-T1-E3 VISHAY	Vishay	500 pcs
	<a href="#">SI7788DP-T1-GE3</a>	MOSFET N-CH 30V 50A PPAK SO-8	Electro-Films (EFI) / Vishay	2196 pcs
	<a href="#">SI7788DP-T1-GE3</a>	MOSFET N-CH 30V 50A PPAK SO-8	Vishay / Siliconix	2196 pcs
	<a href="#">SI7804DN</a>	SI7804DN SI	SI	831 pcs
	<a href="#">SI7784DP-T1-GE3</a>	MOSFET N-CH 30V 35A PPAK SO-8	Electro-Films (EFI) / Vishay	3000 pcs
	<a href="#">SI7792DP-T1-GE3</a>	MOSFET N-CH 30V P-PACK SO-8	Electro-Films (EFI) / Vishay	1000 pcs
	<a href="#">SI7774DP-T1-GE3</a>	MOSFET N-CH 30V 60A PPAK SO-8	Vishay / Siliconix	1000 pcs
	<a href="#">SI7802DN-T1-GE3</a>	MOSFET N-CH 250V 1.24A 1212-8	Electro-Films (EFI) / Vishay	500 pcs
	<a href="#">SI7784DP-T1-GE3</a>	MOSFET N-CH 30V 35A PPAK SO-8	Vishay / Siliconix	3000 pcs
	<a href="#">SI7790DP-T1-GE3</a>	MOSFET N-CH 40V 50A PPAK SO-8	Vishay / Siliconix	798200 pcs
	<a href="#">SI7798DP-T1-GE3</a>	SI7798DP-T1-GE3 VISHAY	Vishay	2231 pcs
	<a href="#">SI7802DN-T1-GE3</a>	MOSFET N-CH 250V 1.24A 1212-8	Vishay / Siliconix	500 pcs
	<a href="#">SI7774DP-T1-GE3</a>	MOSFET N-CH 30V 60A PPAK SO-8	Electro-Films (EFI) / Vishay	1000 pcs
	<a href="#">SI7800ADN</a>	SI7800ADN SI	SI	4 pcs
	<a href="#">SI7802DN-T1-E3</a>	MOSFET N-CH 250V 1.24A 1212-8	Vishay / Siliconix	74 pcs
	<a href="#">SI7804DN-T1-E3</a>	MOSFET N-CH 30V 6.5A 1212-8	Vishay / Siliconix	790 pcs
	<a href="#">SI7790DP-T1-GE3</a>	MOSFET N-CH 40V 50A PPAK SO-8	Electro-Films (EFI) / Vishay	798200 pcs
	<a href="#">SI7804DN-T1-E3</a>	MOSFET N-CH 30V 6.5A 1212-8	Electro-Films (EFI) / Vishay	790 pcs
	<a href="#">SI7802DN</a>	SI7802DN SI	SI	33 pcs

**Chip IC e modulo IGBT - Codice articolo hot spare**

<a href="#">SI7738DP-T1-3</a>	<a href="#">SI7738DP-T1-E3</a>	<a href="#">SI7738DP-T1-E3</a>	<a href="#">SI7738DP-T1-GE3</a>	<a href="#">SI7738DP-T1-GE3</a>
<a href="#">SI7742DP-T1-E3</a>	<a href="#">SI7742DP-T1-GE3</a>	<a href="#">SI7742DP-T1-GE3</a>	<a href="#">SI7748DP-T1-GE3</a>	<a href="#">SI7748DP-T1-GE3</a>
<a href="#">SI7758DP</a>	<a href="#">SI7758DP-T1-GE3</a>	<a href="#">SI7758DP-T1-GE3</a>	<a href="#">SI7772DP-T1-GE3</a>	<a href="#">SI7772DP-T1-GE3</a>
<a href="#">SI7774DP-T1-GE3</a>	<a href="#">SI7774DP-T1-GE3</a>	<a href="#">SI7784DP-T1-GE3</a>	<a href="#">SI7784DP-T1-GE3</a>	<a href="#">SI7788DP-T1-GE3</a>
<a href="#">SI7788DP-T1-GE3</a>	<a href="#">SI7790DP-T1-E3</a>	<a href="#">SI7790DP-T1-GE3</a>	<a href="#">SI7790DP-T1-GE3</a>	<a href="#">SI7792DP-T1-GE3</a>
<a href="#">SI7798DP-T1-GE3</a>	<a href="#">SI7804DN</a>	<a href="#">SI7804DN-T1-E3</a>	<a href="#">SI7804DN-T1-E3</a>	<a href="#">SI7806ADN</a>
<a href="#">SI7806ADN-T1-E3</a>	<a href="#">SI7806ADN-T1-E3</a>	<a href="#">SI7806ADN-T1-E3-PBF</a>	<a href="#">SI7806ADN-T1-GE3</a>	<a href="#">SI7806ADN-T1-GE3</a>
<a href="#">SI7806AEDN-T1-E3</a>	<a href="#">SI7806BDN</a>	<a href="#">SI7806BDN-T1-GE3</a>	<a href="#">SI7806DN-T1-E3</a>	<a href="#">SI7806DN-T1-GE3</a>
<a href="#">SI7810DN</a>	<a href="#">SI7810DN-T1</a>	<a href="#">SI7810DN-T1-E</a>	<a href="#">SI7810DN-T1-E3</a>	<a href="#">SI7810DN-T1-E3</a>
<a href="#">SI7812DN-T1-E3</a>	<a href="#">SI7812DN-T1-E3</a>	<a href="#">SI7812DN-T1-GE3</a>	<a href="#">SI7812DN-T1-GE3</a>	<a href="#">SI7818DN-T1-E3</a>

Distributore componenti elettronici - Chip IC &amp; Fornitore di moduli IGBT.

 Email RFQ: [Info@ariat-tech.com](mailto:Info@ariat-tech.com) Sito web: <https://www.ariat-tech.com>

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